

# 1A, 200V - 1000V Surface Mount Fast Recovery Rectifier

#### **FEATURES**

- Glass passivated junction chip
- · Ideal for automated placement
- Low forward voltage drop
- · Fast switching for high efficiency
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

#### **APPLICATIONS**

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- Converter

#### **MECHANICAL DATA**

- Case: DO-214AC (SMA)
- Molding compound meets UL 94V-0 flammability rating
- Moisture sensitivity level: level 1, per J-STD-020
- Packing code with suffix "G" means green compound (halogen-free)
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: As marked
- Weight: 0.06 g (approximately)

KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
I <sub>F(AV)</sub>	1	Α		
$V_{RRM}$	200 - 1000	<b>V</b>		
I <sub>FSM</sub>	30			
T <sub>J MAX</sub>	150 °C			
Package	DO-214AC (SMA)			
Configuration	Single Die			





DO-214AC (SMA)

PARAMETER	SYMBOL	RS1D-T	RS1G-T	RS1J-T	RS1K-T	RS1M-T	UNIT
Marking code on the device		RS1D	RS1G	RS1J	RS1K	RS1M	
Repetitive peak reverse voltage	$V_{RRM}$	200	400	600	800	1000	V
Reverse voltage, total rms value	$V_{R(RMS)}$	140	280	420	560	700	V
Maximum DC blocking voltage	$V_{DC}$	200	400	600	800	1000	V
Forward current	I <sub>F(AV)</sub>	1			Α		
Surge peak forward current, 8.3 ms single half sine-wave superimposed on rated load per diode)	I <sub>FSM</sub>	30			А		
Junction temperature	T <sub>J</sub>	- 55 to +150				°C	
Storage temperature	T <sub>STG</sub>	- 55 to +150			°C		



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THERMAL PERFORMANCE					
PARAMETER	SYMBOL	TYP	UNIT		
Junction-to-ambient thermal resistance	$R_{\Theta JA}$	105	°C/W		
Junction-to-case thermal resistance	$R_{\Theta JC}$	32	°C/W		

PARAMETER		CONDITIONS	SYMBOL	TYP	MAX	UNIT
Forward voltage per diode (1)		I <sub>F</sub> =1A, T <sub>J</sub> =25°C	$V_{F}$	-	1.3	V
Reverse current @ rated V <sub>R</sub> per diode <sup>(2)</sup>		T <sub>J</sub> = 25°C	I <sub>R</sub>	-	5	μA
		T <sub>J</sub> =125°C		-	50	μA
Junction capacitance		1 MHz, V <sub>R</sub> =4.0V	CJ	10	-	pF
RS1D-T RS1G-T				-	150	ns
Reverse recovery time	RS1J-T	I <sub>F</sub> =0.5A , I <sub>R</sub> =1.0A	t <sub>rr</sub>	-	250	ns
	RS1K-T RS1M-T	I <sub>RR</sub> =0.25A		-	500	ns

#### Notes:

- 1. Pulse test with PW=0.3 ms
- 2. Pulse test with PW=30 ms

ORDERING INFORMATION						
PART NO.	PACKING CODE	PACKING CODE SUFFIX	PACKAGE	PACKING		
	R3		SMA	1,800 / 7" Plastic reel		
RS1x-T (Note 1, 2)	R2	G	SMA	7,500 / 13" Paper reel		
(Note 1, 2)	M2		SMA	7,500 / 13" Plastic reel		

#### Notes:

- 1. "x" defines voltage from 200V (RS1D-T) to 1000V (RS1M-T)
- 2. Whole series with green compound (halogen-free)

EXAMPLE P/N						
EXAMPLE P/N	PART NO.	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION		
RS1M-T R3G	RS1M-T	R3	G	Green compound		



### **CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25°C unless otherwise noted)

Fig1. Forward Current Derating Curve

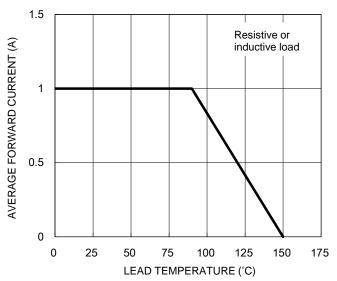


Fig2. Typical Junction Capacitance

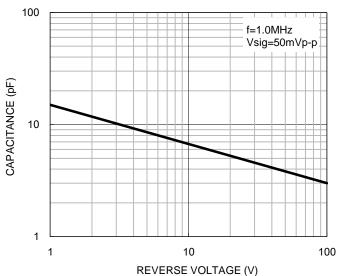


Fig3. Typical Reverse Characteristics

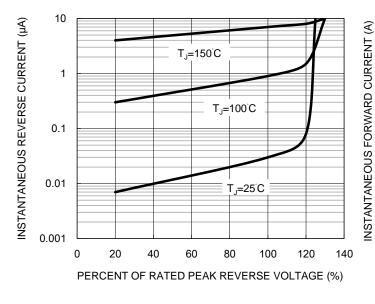
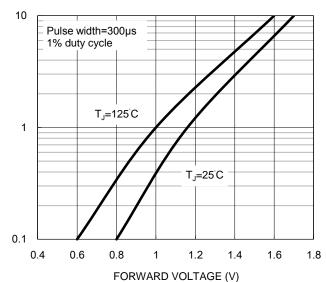


Fig4. Typical Forward Characteristics





### **CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25°C unless otherwise noted)

Fig5. Maximum Non-repetitive Forward Surge Current

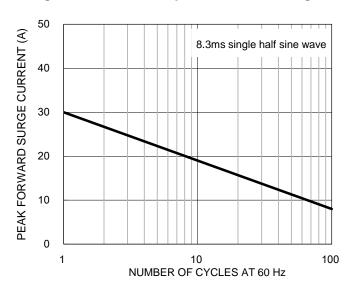
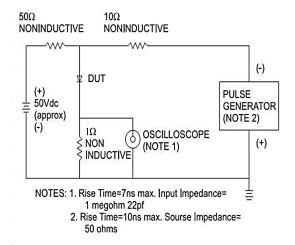
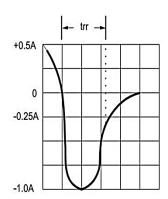


Fig6. Reverse Recovery Time Characteristic And Test Circuit Diagram

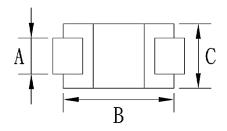


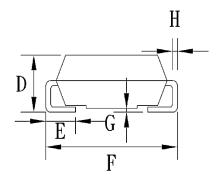




## **PACKAGE OUTLINE DIMENSIONS**

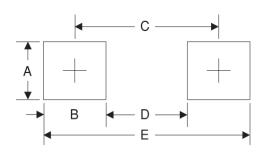
## DO-214AC (SMA)





DIM	Unit (mm)		Unit (	(inch)
	Min	Max	Min	Max
Α	1.27	1.58	0.050	0.062
В	4.06	4.60	0.160	0.181
С	2.29	2.83	0.090	0.111
D	1.99	2.50	0.078	0.098
E	0.90	1.41	0.035	0.056
F	4.95	5.33	0.195	0.210
G	0.10	0.20	0.004	0.008
Н	0.15	0.31	0.006	0.012

## **SUGGESTED PAD LAYOUT**



Symbol	Unit (mm)	Unit (inch)
Α	1.68	0.066
В	1.52	0.060
С	3.93	0.155
D	2.41	0.095
Е	5.45	0.215

### **MARKING DIAGRAM**



= Marking Code= Green Compound P/N G ΥW = Date Code = Factory Code



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